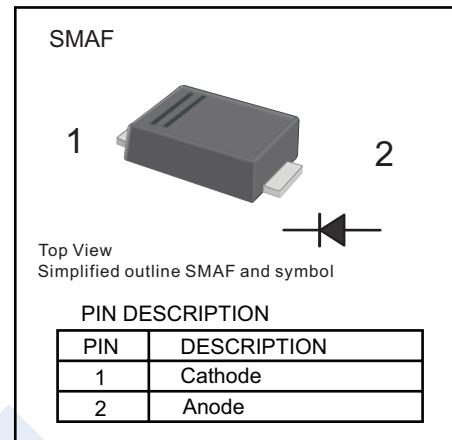


Superfast Recovery Rectifier

ES1AF ~ ES1JF

■ Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



■ Absolute Maximum Ratings Ta = 25°C unless otherwise specified

| Parameter | Symbol | ES 1AF | ES 1BF | ES 1CF | ES 1DF | ES 1EF | ES 1GF | ES 1JF | Unit | | |
|--|--------------------|------------|--------|--------|--------|--------|--------|--------|------|--|--|
| Repetitive Peak Reverse Voltage | V _{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | V | | |
| Surge Peak Reverse Voltage | V _{RSM} | 35 | 70 | 105 | 140 | 210 | 280 | 420 | | | |
| Maximum DC Blocking Voltage | V _{DC} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | | | |
| Instantaneous Forward Voltage at 1A | V _F | 1 | | | | 1.25 | | 1.68 | | | |
| Averaged Forward Current T _C =125°C | I _{F(AV)} | 1 | | | | | | | A | | |
| Peak forward surge current | I _{FSM} | 30 | | | | | | | | | |
| Maximum DC Reverse Current T _A =25°C at rated DC blocking voltage T _A =125°C | I _R | 5 | | | | | | | μA | | |
| Typical Junction Capacitance *1 | | 100 | | | | | | | | | |
| Maximum Reverse Recovery Time *2 | t _{rr} | 15 | | | | | | | pF | | |
| Typical thermal resistance *3 | R _{thJA} | 35 | | | | | | | | | |
| Junction Temperature | T _j | 80 | | | | | | | ns | | |
| Storage Temperature | T _{stg} | 150 | | | | | | | | | |
| * 1 Measured at 1MHz and applied reverse voltage of 4V D.C. | | -55 to 150 | | | | | | | °C/W | | |
| * 2 Measured with I _F = 0.5A, I _R = 1A, I _{rr} = 0.25A. | | | | | | | | | | | |
| * 3. P.C.B mounted with 2" ×2" (35×5 cm) copper pad areas. | | | | | | | | | °C | | |

■ Marking

| NO. | ES1AF | ES1BF | ES1CF | ES1DF | ES1EF | ES1GF | ES1JF |
|---------|-------|-------|-------|-------|-------|-------|-------|
| Marking | ES1A | ES1B | ES1C | ES1D | ES1E | ES1G | ES1J |

Superfast Recovery Rectifier

ES1AF ~ ES1JF

■ Typical Characteristics

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram

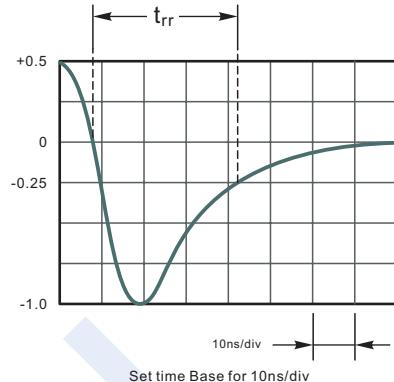
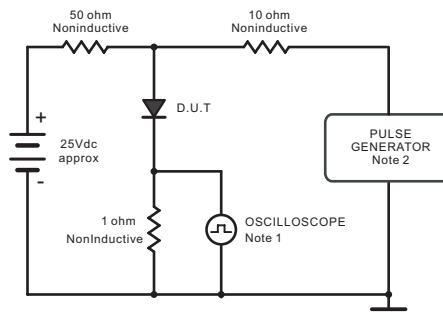


Fig.2 Maximum Average Forward Current Rating

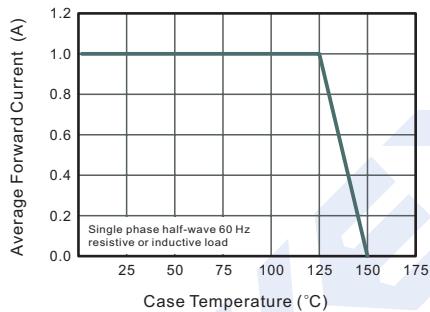


Fig.4 Typical Forward Characteristics

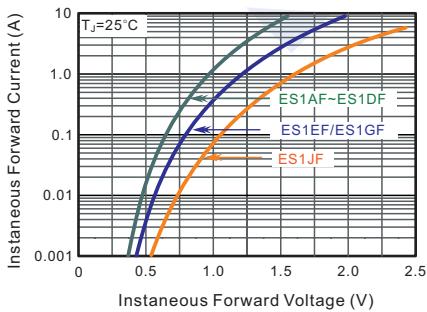


Fig.6 Maximum Non-Repetitive Peak Forward Surge Current

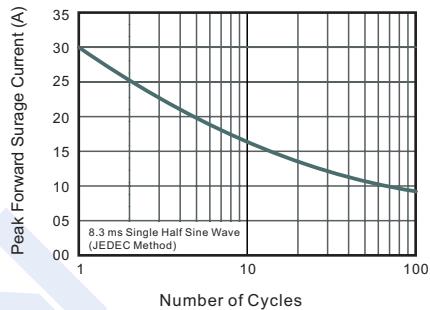


Fig.3 Typical Reverse Characteristics

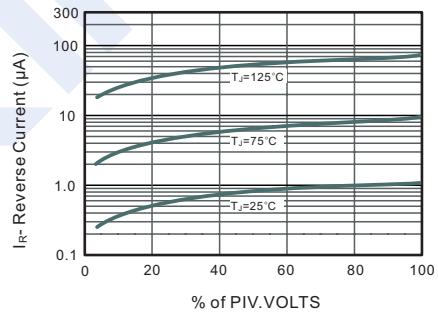
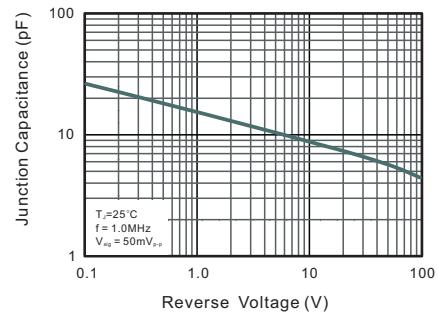


Fig.5 Typical Junction Capacitance



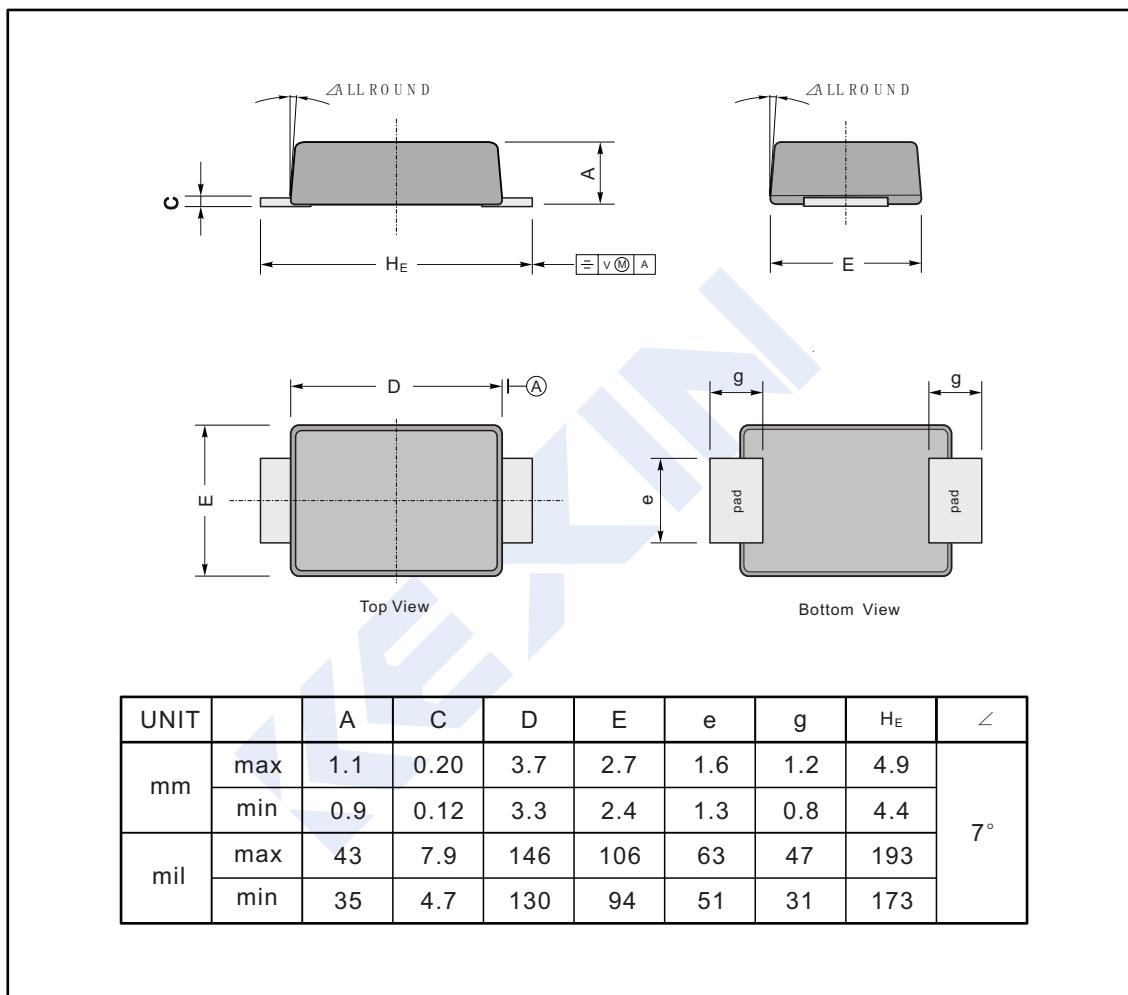
Superfast Recovery Rectifier

ES1AF ~ ES1JF

■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SMAF



■ The Recommended Mounting Pad Size

